

74HC1G126; 74HCT1G126

Bus buffer/line driver; 3-state

Rev. 04 — 20 July 2007

Product data sheet

1. General description

The 74HC1G126 and 74HCT1G126 are high-speed, Si-gate CMOS devices. They provide one non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input pin (OE). A LOW at pin OE causes the output as assume a high-impedance OFF-state.

The HC device has CMOS input switching levels and supply voltage range 2 V to 6 V.

The HCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

The bus driver output currents are equal to those of the 74HC126 and 74HCT126.

2. Features

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options

3. Ordering information

Table 1. Ordering information

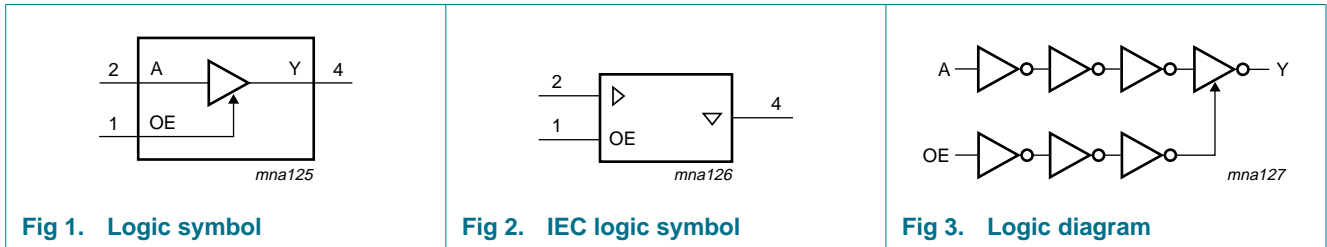
| Type number | Package | | | |
|-----------------------------|-------------------|--------|---|----------|
| | Temperature range | Name | Description | Version |
| 74HC1G126GW 74HCT1G126GW | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 |
| 74HC1G126GV 74HCT1G126GV | -40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads | SOT753 |

4. Marking

Table 2. Marking codes

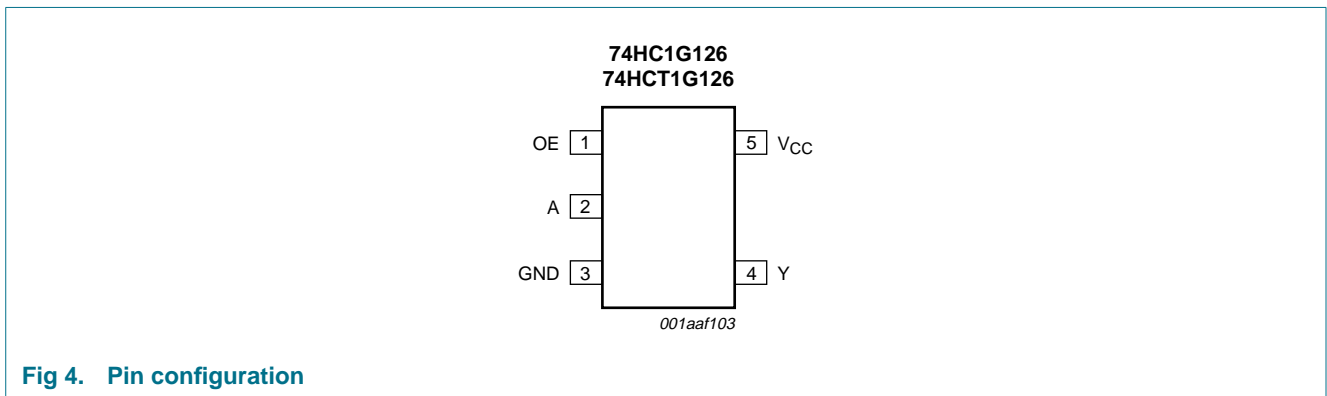
| Type number | Marking |
|--------------|---------|
| 74HC1G126GW | HN |
| 74HCT1G126GW | TN |
| 74HC1G126GV | H26 |
| 74HCT1G126GV | T26 |

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|---------------------|
| OE | 1 | output enable input |
| A | 2 | data input |
| GND | 3 | ground (0 V) |
| Y | 4 | data output |
| V _{CC} | 5 | supply voltage |

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state

| Inputs | | Output |
|--------|---|--------|
| OE | A | Y |
| H | L | L |
| H | H | H |
| L | X | Z |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V). [\[1\]](#)

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|--|-----------------------|------------|------|
| V_{CC} | supply voltage | | -0.5 | +7.0 | V |
| I_{IK} | input clamping current | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ | - | ± 20 | mA |
| I_{OK} | output clamping current | $V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ | - | ± 20 | mA |
| I_O | output current | $-0.5\text{ V} < V_O < V_{CC} + 0.5\text{ V}$ | - | ± 35.0 | mA |
| I_{CC} | supply current | | - | 70 | mA |
| I_{GND} | ground current | | -70 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40\text{ °C to }+125\text{ °C}$ | [2] - | 200 | mW |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] Above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 74HC1G126 | | | 74HCT1G126 | | | Unit |
|---------------------|-------------------------------------|-------------------------|-----------|-----|----------|------------|-----|----------|------|
| | | | Min | Typ | Max | Min | Typ | Max | |
| V_{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | 4.5 | 5.0 | 5.5 | V |
| V_I | input voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| V_O | output voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 2.0\text{ V}$ | - | - | 625 | - | - | - | ns/V |
| | | $V_{CC} = 4.5\text{ V}$ | - | - | 139 | - | - | 139 | ns/V |
| | | $V_{CC} = 6.0\text{ V}$ | - | - | 83 | - | - | - | ns/V |

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V). All typical values are measured at $T_{amb} = 25\text{ °C}$.

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|---------------------------|--------------------------|-------------------------|------------------|-----|------|-------------------|------|------|
| | | | Min | Typ | Max | Min | Max | |
| For type 74HC1G126 | | | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 2.0\text{ V}$ | 1.5 | 1.2 | - | 1.5 | - | V |
| | | $V_{CC} = 4.5\text{ V}$ | 3.15 | 2.4 | - | 3.15 | - | V |
| | | $V_{CC} = 6.0\text{ V}$ | 4.2 | 3.2 | - | 4.2 | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 2.0\text{ V}$ | - | 0.8 | 0.5 | - | 0.5 | V |
| | | $V_{CC} = 4.5\text{ V}$ | - | 2.1 | 1.35 | - | 1.35 | V |
| | | $V_{CC} = 6.0\text{ V}$ | - | 2.8 | 1.8 | - | 1.8 | V |

Table 7. Static characteristics ...continued

Voltages are referenced to GND (ground = 0 V). All typical values are measured at $T_{amb} = 25\text{ }^{\circ}\text{C}$.

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit |
|----------------------------|---------------------------|--|------------------|------|------|-------------------|-----|------|
| | | | Min | Typ | Max | Min | Max | |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | 6.0 | - | 5.9 | - | V |
| | | I _O = -6.0 mA; V _{CC} = 4.5 V | 3.84 | 4.32 | - | 3.7 | - | V |
| | | I _O = -7.8 mA; V _{CC} = 6.0 V | 5.34 | 5.81 | - | 5.2 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 6.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.33 | - | 0.4 | V |
| | | I _O = 7.8 mA; V _{CC} = 6.0 V | - | 0.16 | 0.33 | - | 0.4 | V |
| I _I | input leakage current | V _I = V _{CC} or GND; V _{CC} = 6.0 V | - | - | 1.0 | - | 1.0 | μA |
| I _{OZ} | OFF-state output current | V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND; V _{CC} = 6.0 V | - | - | 5 | - | 10 | μA |
| I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V | - | - | 10 | - | 20 | μA |
| C _I | input capacitance | | - | 1.5 | - | - | - | pF |
| For type 74HCT1G126 | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | 1.6 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | 1.2 | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | |
| | | I _O = -20 μA | 4.4 | 4.5 | - | 4.4 | - | V |
| | | I _O = -6.0 mA | 3.84 | 4.32 | - | 3.7 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | |
| | | I _O = 20 μA | - | 0 | 0.1 | - | 0.1 | V |
| | | I _O = 6.0 mA | - | 0.16 | 0.33 | - | 0.4 | V |
| I _I | input leakage current | V _I = V _{CC} or GND; V _{CC} = 5.5 V | - | - | 1.0 | - | 1.0 | μA |
| I _{OZ} | OFF-state output current | V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND; V _{CC} = 5.5 V | - | - | 5 | - | 10 | |
| I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V | - | - | 10 | - | 20 | μA |
| ΔI _{CC} | additional supply current | per input; V _{CC} = 4.5 V to 5.5 V; V _I = V _{CC} - 2.1 V; I _O = 0 A | - | - | 500 | - | 850 | μA |
| C _I | input capacitance | | - | 1.5 | - | - | - | pF |

11. Dynamic characteristics

Table 8. Dynamic characteristics

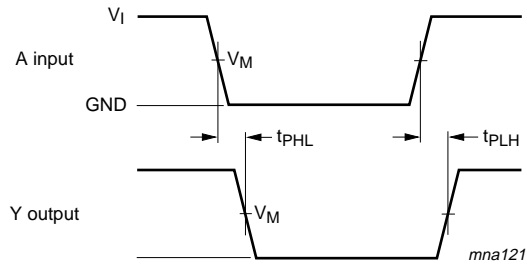
$GND = 0\text{ V}$; $t_r = t_f \leq 6.0\text{ ns}$; $C_L = 50\text{ pF}$ unless otherwise specified. All typical values are measured at $T_{amb} = 25\text{ }^\circ\text{C}$. For test circuit see [Figure 7](#)

| Symbol | Parameter | Conditions | -40 °C to +85 °C | | | -40 °C to +125 °C | | Unit | |
|----------------------------|-------------------------------|---|---------------------|-----|-----|-------------------|-----|------|----|
| | | | Min | Typ | Max | Min | Max | | |
| For type 74HC1G126 | | | | | | | | | |
| t_{pd} | propagation delay | A to Y; see Figure 5 | [1] | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | - | 24 | 125 | - | 150 | ns | |
| | | $V_{CC} = 4.5\text{ V}$ | - | 10 | 25 | - | 30 | ns | |
| | | $V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$ | - | 9 | - | - | - | ns | |
| | | $V_{CC} = 6.0\text{ V}$ | - | 9 | 21 | - | 26 | ns | |
| t_{en} | enable time | OE to Y; see Figure 6 | [1] | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | - | 24 | 155 | - | 190 | ns | |
| | | $V_{CC} = 4.5\text{ V}$ | - | 10 | 31 | - | 38 | ns | |
| | | $V_{CC} = 6.0\text{ V}$ | - | 8 | 26 | - | 32 | ns | |
| t_{dis} | disable time | OE to Y; see Figure 6 | [1] | | | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | - | 16 | 155 | - | 190 | ns | |
| | | $V_{CC} = 4.5\text{ V}$ | - | 12 | 31 | - | 38 | ns | |
| | | $V_{CC} = 6.0\text{ V}$ | - | 11 | 26 | - | 32 | ns | |
| C_{PD} | power dissipation capacitance | $V_I = GND\text{ to }V_{CC}$ | [2] | - | 30 | - | - | - | pF |
| For type 74HCT1G126 | | | | | | | | | |
| t_{pd} | propagation delay | A to Y; see Figure 5 | [1] | | | | | | |
| | | $V_{CC} = 4.5\text{ V}$ | - | 11 | 30 | - | 36 | ns | |
| | | $V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$ | - | 10 | - | - | - | ns | |
| t_{en} | enable time | OE to Y; see Figure 6 ; $V_{CC} = 4.5\text{ V}$ | [1] | - | 10 | 35 | - | 42 | ns |
| t_{dis} | disable time | OE to Y; see Figure 6 ; $V_{CC} = 4.5\text{ V}$ | [1] | - | 12 | 31 | - | 38 | ns |
| C_{PD} | power dissipation capacitance | $V_I = GND\text{ to }V_{CC} - 1.5\text{ V}$ | [2] | - | 27 | - | - | - | pF |

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
 t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{dis} is the same as t_{PLZ} and t_{PHZ} .

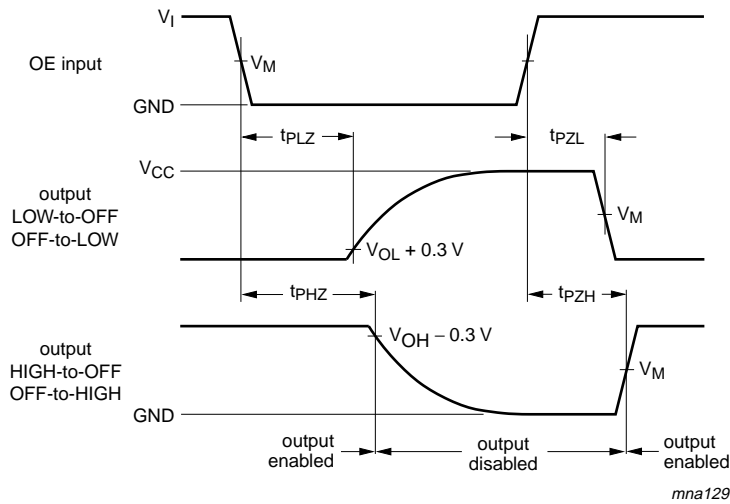
- [2] C_{PD} is used to determine the dynamic power dissipation P_D (μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz
 f_o = output frequency in MHz
 C_L = output load capacitance in pF
 V_{CC} = supply voltage in Volts
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

12. Waveforms



Measurement points are given in [Table 9](#).

Fig 5. The input (A) to output (Y) propagation delays

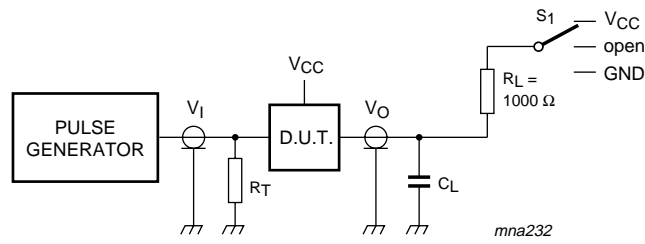


Measurement points are given in [Table 9](#).

Fig 6. The 3-state enable and disable times

Table 9. Measurement points

| Type | Input | | Output |
|------------|---------------------|-----------------|---------------------|
| | V_M | V_I | V_M |
| 74HC1G126 | $0.5 \times V_{CC}$ | GND to V_{CC} | $0.5 \times V_{CC}$ |
| 74HCT1G126 | 1.3 V | GND to 3.0 V | 1.3 V |



Test data is given in [Table 8](#). Definitions for test circuit:

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistance

For t_{PLH} , t_{PHL} , S_1 = open

For t_{PLZ} , t_{PZL} , S_1 = V_{CC}

For t_{PHZ} , t_{PZH} , S_1 = GND

Fig 7. Load circuitry for switching times

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

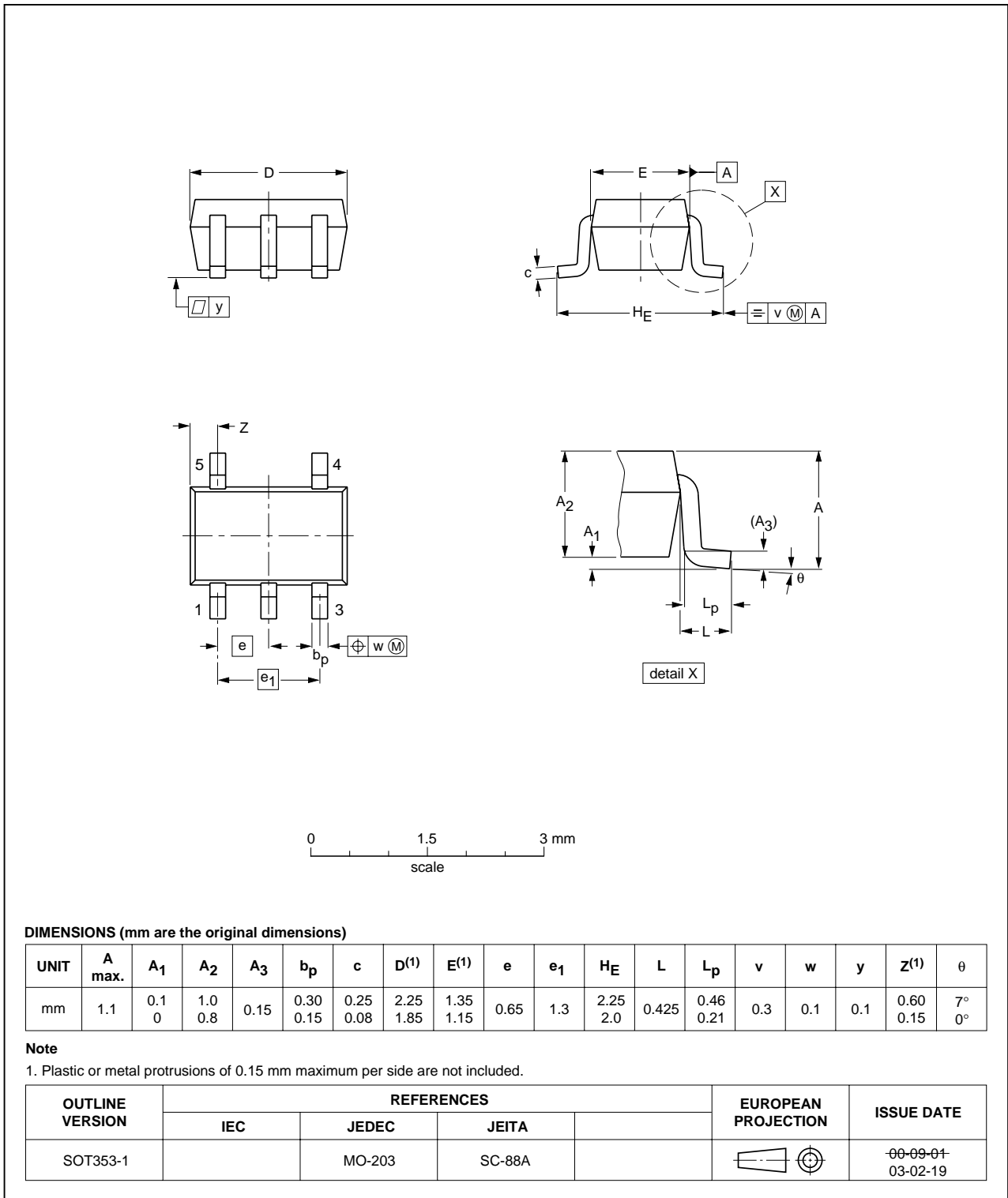


Fig 8. Package outline SOT353-1 (TSSOP5)

Plastic surface-mounted package; 5 leads

SOT753



Fig 9. Package outline SOT753 (SC-74A)

14. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|-----------------------------|
| DUT | Device Under Test |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------|--------------|---|---------------|-----------------|
| 74HC_HCT1G126_4 | 20070720 | Product data sheet | - | 74HC_HCT1G126_3 |
| Modifications: | | <ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.• Package SOT353 changed to SOT353-1 in Table 1 and Figure 8.• Quick Reference Data and Soldering sections removed.• Section 2 "Features" updated. | | |
| 74HC_HCT1G126_3 | 20020515 | Product specification | - | 74HC_HCT1G126_2 |
| 74HC_HCT1G126_2 | 20010406 | Product specification | - | 74HC_HCT1G126 |
| 74HC_HCT1G126 | 19970924 | Preliminary specification | - | - |

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16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
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